VS-VSKCS200/045

Vishay Semiconductors





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PRODUCT SUMMARY					
I _{F(AV)}	200 A				
V _R	45 V				
Package	AAP GEN VII (TO-240AA)				
Circuit	Two diodes common cathode				

MECHANICAL DESCRIPTION

The ADD-A-PAK generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- Low thermal resistance
- UL pending
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- Easy mounting on heatsink

ELECTRICAL DESCRIPTION

The VS-VSKCS200/45 Schottky rectifier common cathode has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	200	А				
V _{RRM}		45	V				
I _{FSM}	t _p = 5 μs sine	12 800	А				
V _F	100 A _{pk} , T _J = 125 °C	0.73	V				
TJ	Range	-55 to +150	°C				

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-VSKCS200/045	UNITS			
Maximum DC reverse voltage	V _R	45	V			
Maximum working peak reverse voltage	V _{RWM}	45	v			



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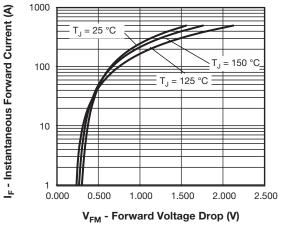
ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average	per module		50 % duty cycle at T_{C} = 91 °C, rectangular waveform		200	А
forward current	per leg	I _{F(AV)}	50% duty cycle at $1^\circ_{\rm C} = 91^\circ_{\rm C}$,	100		
Maximum peak one cycle		1	5 μs sine or 3 μs rect. pulse Following any rated 10 ms sine or 6 ms rect. pulse load condition and with rated V _{RRM} applied		12 800	
non-repetitive surge current		I _{FSM}			1700	
Non-repetitive avalanche energy		E _{AS}	T _J = 25 °C, I _{AS} = 19 A, L = 1 mH		180	mJ
Repetitive avalanche current		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		15	А

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
		100 A	T _{.1} = 25 °C	0.67		
Maximum forward voltage drop	V	200 A	0.92	v		
Maximum forward voltage drop	V _{FM}	100 A	T _ 125 °C	0.73	v	
		T_J = 125 °C	1j = 125 C	1.14		
Maximum reverse leakage current		T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	10	mA	
Maximum reverse leakage current	I _{RM}	T _J = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	800		
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		5200	pF	
Typical series inductance	Ls	Measured lead to lead 5 mm from package body		7.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs	
Maximum RMS insulation voltage	V _{INS}	50 Hz		3000 (1 min) 3600 (1 s)	V	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +150	°C	
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	0.52	°C/W	
Typical thermal resistance, case to heatsink per module		R _{thCS}		0.1	0/00	
Approximate weight				75	g	
				2.7	oz.	
Mounting torgue ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the	4	Nm	
	busbar		spread of the compound.	3		
Case style			JEDEC®	TO-240AA co	mpatible	

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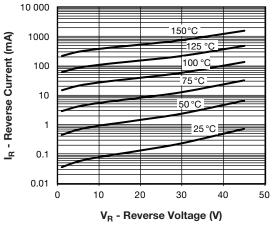
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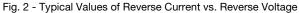


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Fig. 1 - Maximum Forward Voltage Drop Characteristics





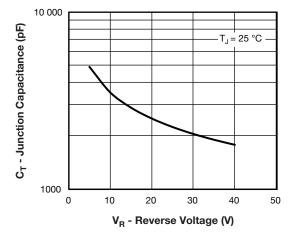


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

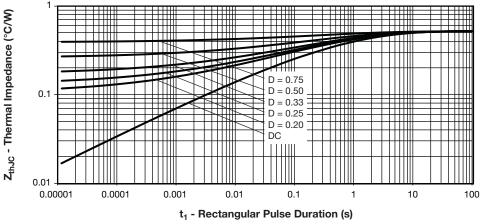
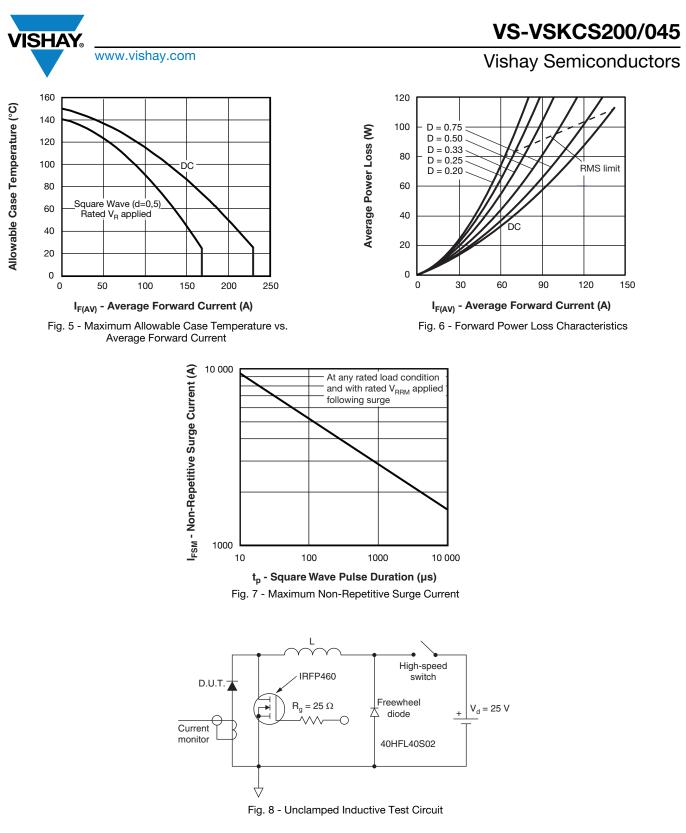


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
- Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 D)$; I_R at V_{R1} = 80 % rated V_R

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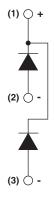
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ORDERING INFORMATION TABLE

Device code	VS-VS	KC	S	20	0	1	045	
	1	2	3	4	5		6	
	1 - 2 - 3 - 4 - 5 - 6 -	Circ KC S = Ave Pro	nay Sem cuit conf = ADD-, Schottk erage cu duct silio tage rati	iguratior A-PAK - y diode rrent rat con iden	n: • 2 diode ing (20 •tificatio	es/comr = 200 A n	non cath	node

CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95369				

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ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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